



Is Now Part of



**ON Semiconductor®**

To learn more about ON Semiconductor, please visit our website at  
[www.onsemi.com](http://www.onsemi.com)

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (\_), the underscore (\_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (\_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at [www.onsemi.com](http://www.onsemi.com). Please email any questions regarding the system integration to [Fairchild\\_questions@onsemi.com](mailto:Fairchild_questions@onsemi.com).

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at [www.onsemi.com/site/pdf/Patent-Marking.pdf](http://www.onsemi.com/site/pdf/Patent-Marking.pdf). ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

# KA5x02xx-SERIES

KA5H0265RC, KA5M0265R, KA5L0265R,  
KA5H02659RN/KA5M02659RN, KA5H0280R,  
KA5M0280R

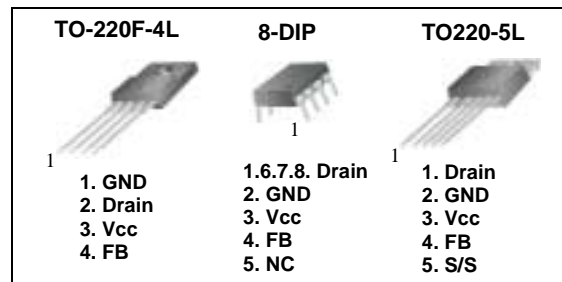
## Fairchild Power Switch(FPS)

### Features

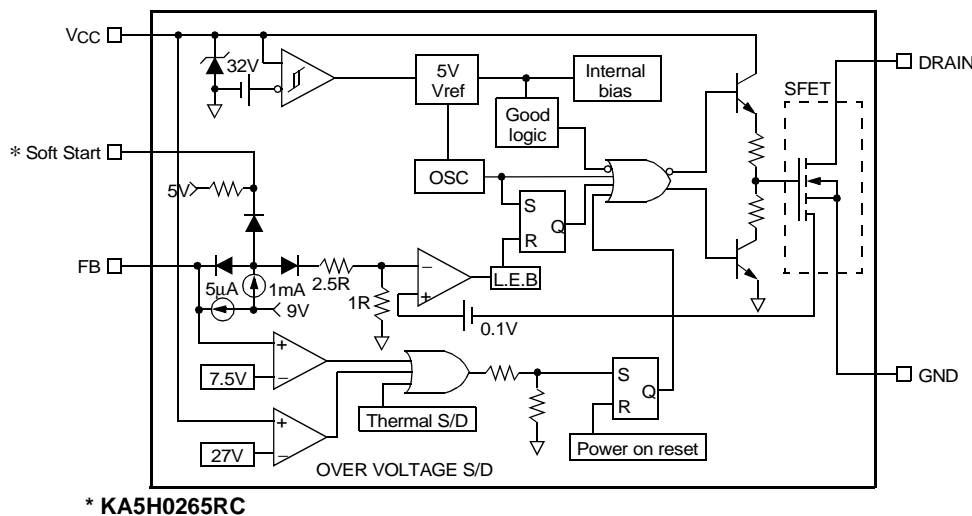
- Precision Fixed Operating Frequency (100/67/50kHz)
- Low Start-up Current (Typ. 100uA)
- Pulse by Pulse Current Limiting
- Over Load Protection
- Over Voltage Protection (Min. 25V)
- Internal Thermal Shutdown Function
- Under Voltage Lockout
- Internal High Voltage Sense FET
- Auto-Restart Mode

### Description

The Fairchild Power Switch(FPS) product family is specially designed for an off-line SMPS with minimal external components. The Fairchild Power Switch(FPS) consist of high voltage power SenseFET and current mode PWM IC. Included PWM controller features integrated fixed oscillator, under voltage lock out, leading edge blanking, optimized gate turn-on/turn-off driver, thermal shut down protection, over voltage protection, and temperature compensated precision current sources for loop compensation and fault protection circuitry-compared to discrete MOSFET and controller or RCC switching converter solution. The Fairchild Power Switch(FPS) can reduce total component count, design size, weight and at the same time increase efficiency, productivity, and system reliability. It has a basic platform well suited for cost-effective design in either a flyback converter or a forward converter.



### Internal Block Diagram



## Absolute Maximum Ratings

(Ta=25°C, unless otherwise specified)

Characteristic	Symbol	Value	Unit
<b>KA5x0265xRx</b>			
Drain-Gate Voltage (R <sub>GS</sub> =1MΩ)	V <sub>DGR</sub>	650	V
Gate-Source (GND) Voltage	V <sub>GS</sub>	±30	V
Drain Current Pulsed <sup>(1)</sup>	I <sub>DM</sub>	8.0	ADC
Continuous Drain Current (T <sub>C</sub> =25°C)	I <sub>D</sub>	2.0	ADC
Continuous Drain Current (T <sub>C</sub> =100°C)	I <sub>D</sub>	1.3	ADC
Single Pulsed Avalanche Energy <sup>(2)</sup>	E <sub>AS</sub>	68	mJ
Maximum Supply Voltage	V <sub>CC,MAX</sub>	30	V
Analog Input Voltage Range	V <sub>FB</sub>	-0.3 to V <sub>SD</sub>	V
Total Power Dissipation	P <sub>D</sub>	42	W
	Darting	0.33	W/°C
Operating Junction Temperature.	T <sub>J</sub>	+160	°C
Operating Ambient Temperature.	T <sub>A</sub>	-25 to +85	°C
Storage Temperature Range.	T <sub>STG</sub>	-55 to +150	°C
<b>KA5x0280R</b>			
Drain-Gate Voltage (R <sub>GS</sub> =1MΩ)	V <sub>DGR</sub>	800	V
Gate-Source (GND) Voltage	V <sub>GS</sub>	±30	V
Drain Current Pulsed <sup>(1)</sup>	I <sub>DM</sub>	8.0	ADC
Continuous Drain Current (T <sub>C</sub> =25°C)	I <sub>D</sub>	2.0	ADC
Continuous Drain Current (T <sub>C</sub> =100°C)	I <sub>D</sub>	1.3	ADC
Single Pulsed Avalanche Energy <sup>(2)</sup>	E <sub>AS</sub>	90	mJ
Maximum Supply Voltage	V <sub>CC,MAX</sub>	30	V
Analog Input Voltage Range	V <sub>FB</sub>	-0.3 to V <sub>SD</sub>	V
Total Power Dissipation	P <sub>D</sub>	35	W
	Darting	0.28	W/°C
Operating Junction Temperature.	T <sub>J</sub>	+160	°C
Operating Ambient Temperature.	T <sub>A</sub>	-25 to +85	°C
Storage Temperature Range.	T <sub>STG</sub>	-55 to +150	°C

**Note:**

1. Repetitive rating: Pulse width limited by maximum junction temperature
2. L = 51mH, starting T<sub>j</sub> = 25°C

## Electrical Characteristics (SFET Part)

(Ta=25°C unless otherwise specified)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
<b>KA5x0265xRx</b>						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =50μA	650	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =Max. Rating, V <sub>GS</sub> =0V	-	-	50	μA
		V <sub>DS</sub> =0.8Max. Rating, V <sub>GS</sub> =0V, T <sub>C</sub> =125°C	-	-	200	μA
Static Drain-Source on Resistance <sup>(Note)</sup>	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =0.5A	-	5.0	6.0	Ω
Forward Transconductance <sup>(Note)</sup>	g <sub>fs</sub>	V <sub>DS</sub> =50V, I <sub>D</sub> =0.5A	1.5	2.5	-	S
Input Capacitance	C <sub>iss</sub>	V <sub>GS</sub> =0V, V <sub>DS</sub> =25V, f=1MHz	-	550	-	pF
Output Capacitance	C <sub>oss</sub>		-	38	-	
Reverse Transfer Capacitance	C <sub>rss</sub>		-	17	-	
Turn on Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> =0.5B V <sub>DSS</sub> , I <sub>D</sub> =1.0A (MOSFET switching time is essentially independent of operating temperature)	-	20	-	nS
Rise Time	t <sub>r</sub>		-	15	-	
Turn Off Delay Time	t <sub>d(off)</sub>		-	55	-	
Fall Time	t <sub>f</sub>		-	25	-	
Total Gate Charge (Gate-Source+Gate-Drain)	Q <sub>g</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =1.0A, V <sub>DS</sub> =0.5B V <sub>DSS</sub> (MOSFET switching time is essentially independent of operating temperature)	-	-	35	nC
Gate-Source Charge	Q <sub>gs</sub>		-	3	-	
Gate-Drain (Miller) Charge	Q <sub>gd</sub>		-	12	-	
<b>KA5x0280R</b>						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =50μA	800	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =Max. Rating, V <sub>GS</sub> =0V	-	-	50	μA
		V <sub>DS</sub> =0.8Max. Rating, V <sub>GS</sub> =0V, T <sub>C</sub> =125°C	-	-	200	μA
Static Drain-Source on Resistance <sup>(Note)</sup>	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =0.5A	-	5.6	7.0	Ω
Forward Transconductance <sup>(Note)</sup>	g <sub>fs</sub>	V <sub>DS</sub> =50V, I <sub>D</sub> =0.5A	1.5	2.5	-	S
Input Capacitance	C <sub>iss</sub>	V <sub>GS</sub> =0V, V <sub>DS</sub> =25V, f=1MHz	-	250	-	pF
Output Capacitance	C <sub>oss</sub>		-	52	-	
Reverse Transfer Capacitance	C <sub>rss</sub>		-	25	-	
Turn on Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> =0.5B V <sub>DSS</sub> , I <sub>D</sub> =1.0A (MOSFET switching time is essentially independent of operating temperature)	-	21	-	nS
Rise Time	t <sub>r</sub>		-	28	-	
Turn Off Delay Time	t <sub>d(off)</sub>		-	77	-	
Fall Time	t <sub>f</sub>		-	24	-	
Total Gate Charge (Gate-Source+Gate-Drain)	Q <sub>g</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =1.0A, V <sub>DS</sub> =0.5B V <sub>DSS</sub> (MOSFET switching time is essentially independent of operating temperature)	-	-	60	nC
Gate-Source Charge	Q <sub>gs</sub>		-	15	-	
Gate-Drain (Miller) Charge	Q <sub>gd</sub>		-	20	-	

### Note:

1. Pulse test: Pulse width ≤ 300μs, duty cycle ≤ 2%

$$2. S = \frac{1}{R}$$

**Electrical Characteristics (Control Part)** (Continued)

(Ta=25°C unless otherwise specified)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
<b>UVLO SECTION</b>						
Start Threshold Voltage	V <sub>START</sub>	V <sub>FB</sub> =GND	14	15	16	V
Stop Threshold Voltage	V <sub>STOP</sub>	V <sub>FB</sub> =GND	8.2	8.8	9.4	V
<b>OSCILLATOR SECTION</b>						
Initial Accuracy	F <sub>OSC</sub>	KA5H0265xRx KA5H0280R	90	100	110	kHz
Initial Accuracy	F <sub>OSC</sub>	KA5M0265xRx KA5M0280R	61	67	73	kHz
Initial Accuracy	F <sub>OSC</sub>	KA5L0265R	45	50	55	kHz
Frequency Change With Temperature <sup>(2)</sup>	ΔF/ΔT	-25°C ≤ Ta ≤ +85°C	-	±5	±10	%
Maximum Duty Cycle	D <sub>max</sub>	KA5H0265xRx KA5H0280R	62	67	72	%
Maximum Duty Cycle	D <sub>max</sub>	KA5M0265xRx KA5M0280R KA5L0265R	72	77	82	%
<b>FEEDBACK SECTION</b>						
Feedback Source Current	I <sub>FB</sub>	Ta=25°C, 0V ≤ V <sub>fb</sub> ≤ 3V	0.7	0.9	1.1	mA
Shutdown Feedback Voltage	V <sub>SD</sub>	V <sub>fb</sub> ≤ 6.5V	6.9	7.5	8.1	V
Shutdown Delay Current	I <sub>delay</sub>	Ta=25°C, 5V ≤ V <sub>fb</sub> ≤ V <sub>SD</sub>	4	5	6	μA
<b>SOFT START SECTION</b>						
Soft Start Voltage	V <sub>SS</sub>	KA5H0265RC	4.7	5.0	5.3	V
Soft Start Current	I <sub>SS</sub>		0.8	1.0	1.2	mA
<b>REFERENCE SECTION</b>						
Output Voltage <sup>(1)</sup>	V <sub>ref</sub>	Ta=25°C	4.80	5.00	5.20	V
Temperature Stability <sup>(1)(2)</sup>	V <sub>ref</sub> /ΔT	-25°C ≤ Ta ≤ +85°C	-	0.3	0.6	mV/°C
<b>CURRENT LIMIT(SELF-PROTECTION)SECTION</b>						
Peak Current Limit	I <sub>OVER</sub>	KA5x02659RN	0.79	0.9	1.01	A
Peak Current Limit	I <sub>OVER</sub>	KA5x0265Rx KA5x0280R	1.05	1.2	1.34	A
<b>PROTECTION SECTION</b>						
Over Voltage Protection	V <sub>OVP</sub>	V <sub>CC</sub> ≥ 24V	25	27	29	V
Thermal Shutdown Temperature <sup>(1)</sup>	T <sub>SD</sub>	-	140	160	-	°C
<b>TOTAL DEVICE SECTION</b>						
Start-up Current	I <sub>START</sub>	V <sub>CC</sub> =14V	-	100	170	μA
Operating Supply Current (Control Part Only)	I <sub>OPR</sub>	V <sub>CC</sub> ≤ 28	-	7	12	mA

**Note:**

1. These parameters, although guaranteed, are not 100% tested in production
2. These parameters, although guaranteed, are tested in EDS (wafer test) process

# Typical Performance Characteristics

(These characteristic graphs are normalized at Ta=25°C)

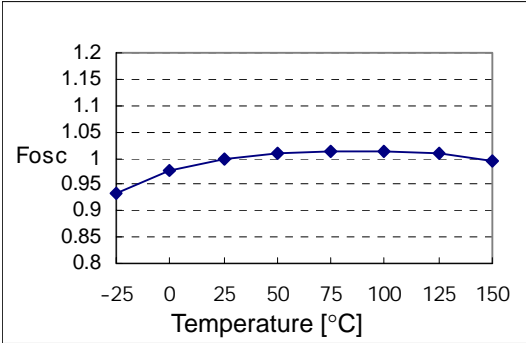


Figure 1. Operating Frequency

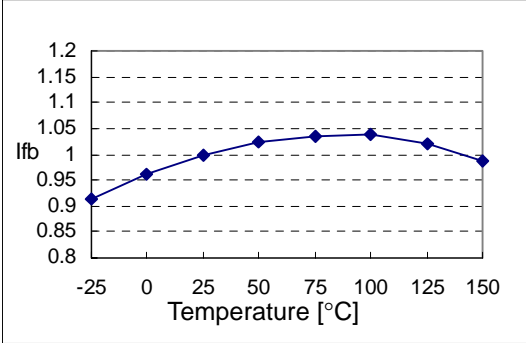


Figure 2. Feedback Source Current

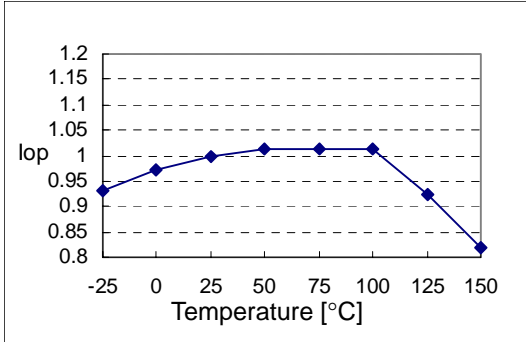


Figure 3. Operating Supply Current

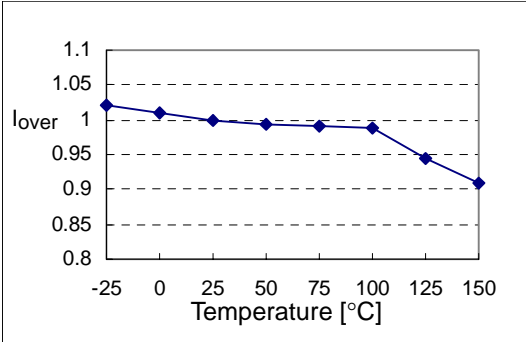


Figure 4. Peak Current Limit

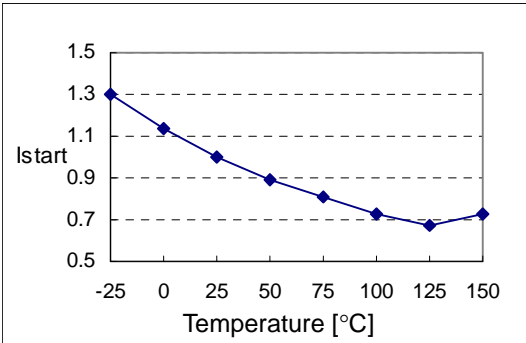


Figure 5. Start up Current

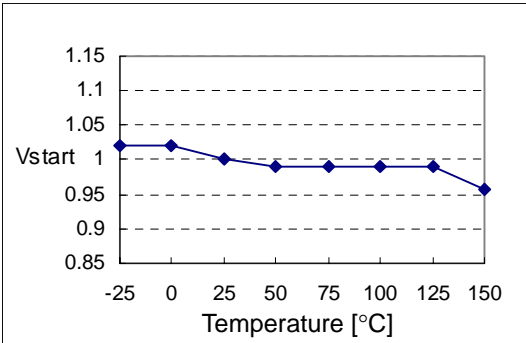
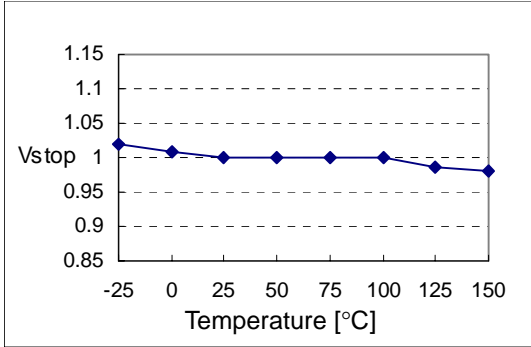


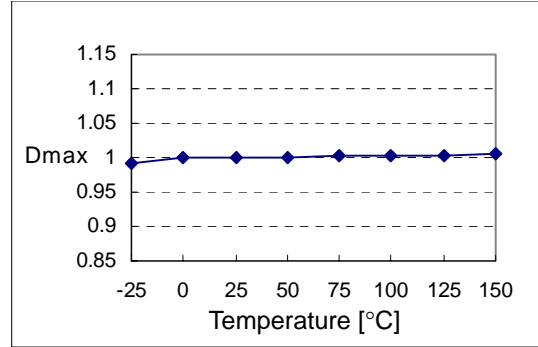
Figure 6. Start Threshold Voltage

**Typical Performance Characteristics** (Continued)

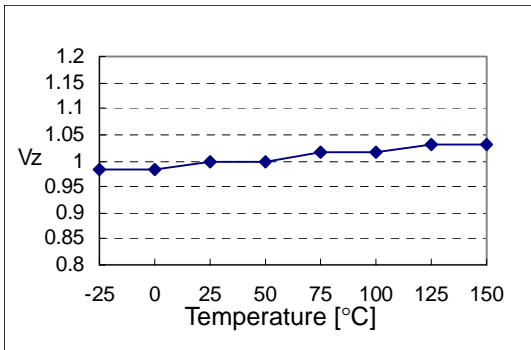
(These characteristic graphs are normalized at  $T_a=25^\circ\text{C}$ )



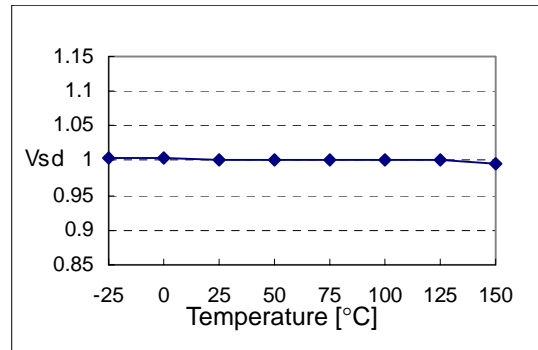
**Figure 7. Stop Threshold Voltage**



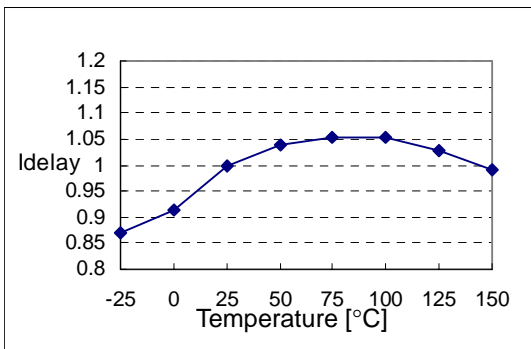
**Figure 8. Maximum Duty Cycle**



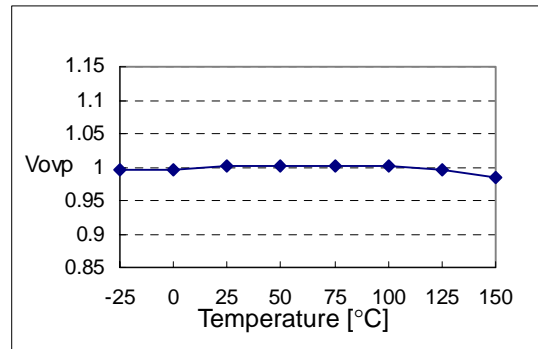
**Figure 9. VCC Zener Voltage**



**Figure 10. Shutdown Feedback Voltage**



**Figure 11. Shutdown Delay Current**



**Figure 12. Over Voltage Protection**

**Typical Performance Characteristics** (Continued)

(These characteristic graphs are normalized at Ta=25°C)

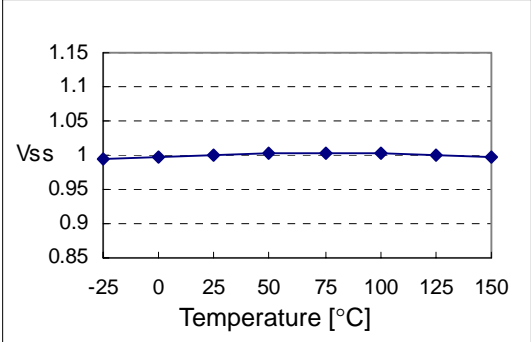


Figure13. Soft Start Voltage

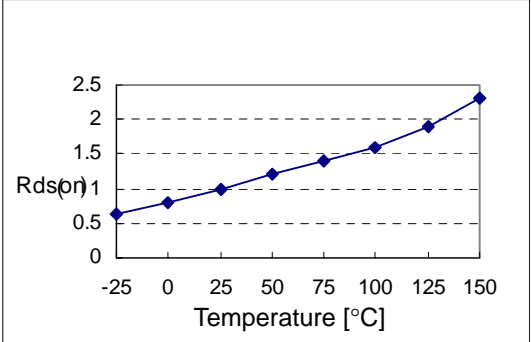


Figure 14. Static Drain-Source on Resistance

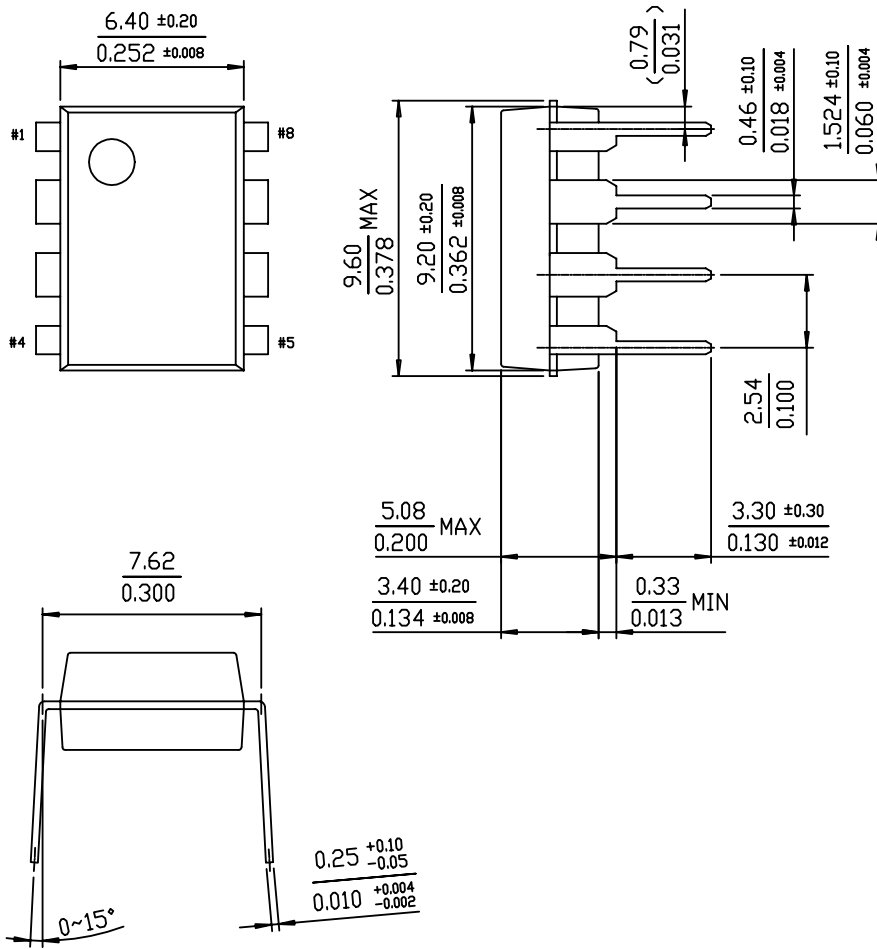






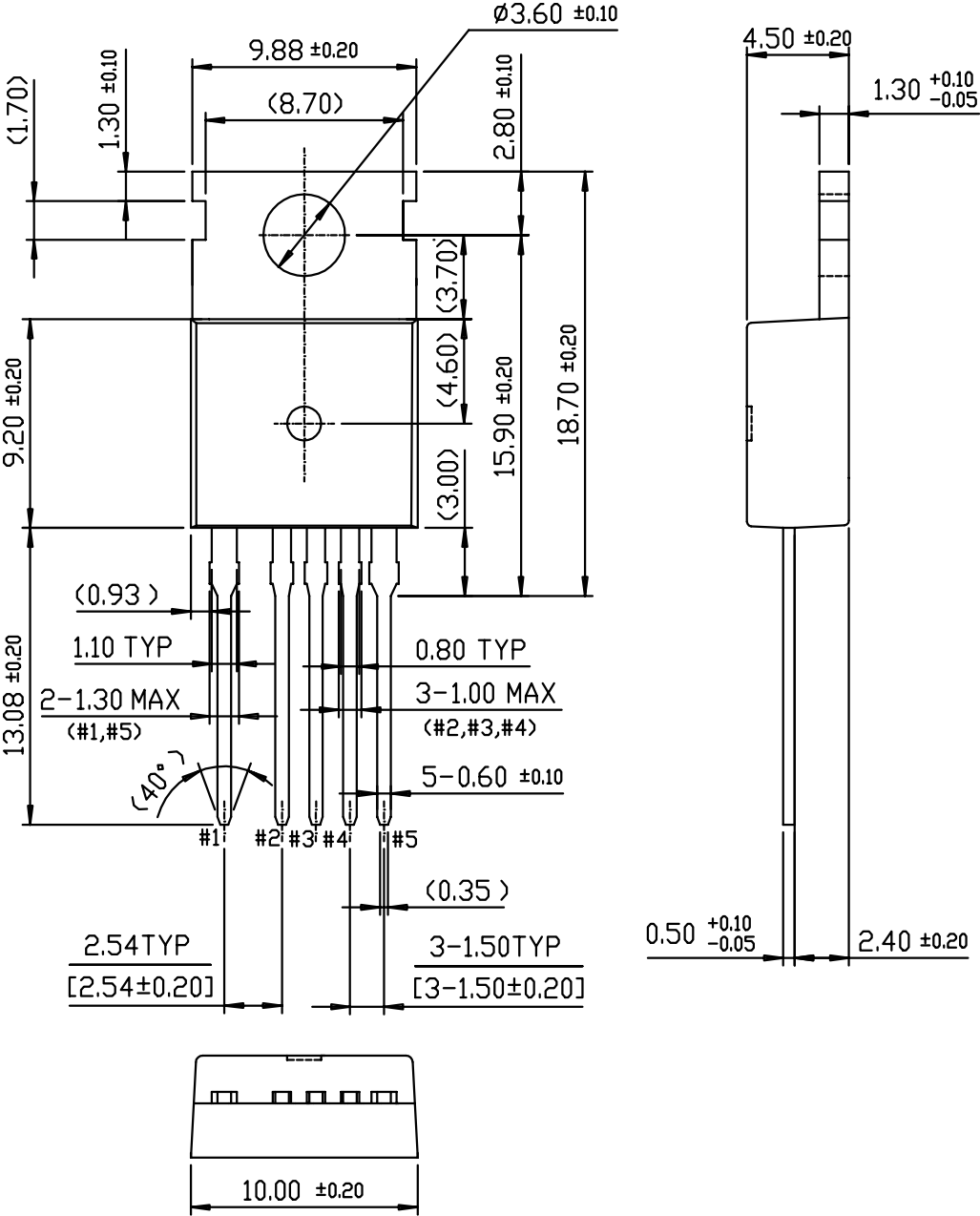
Package Dimensions (Continued)

8-DIP



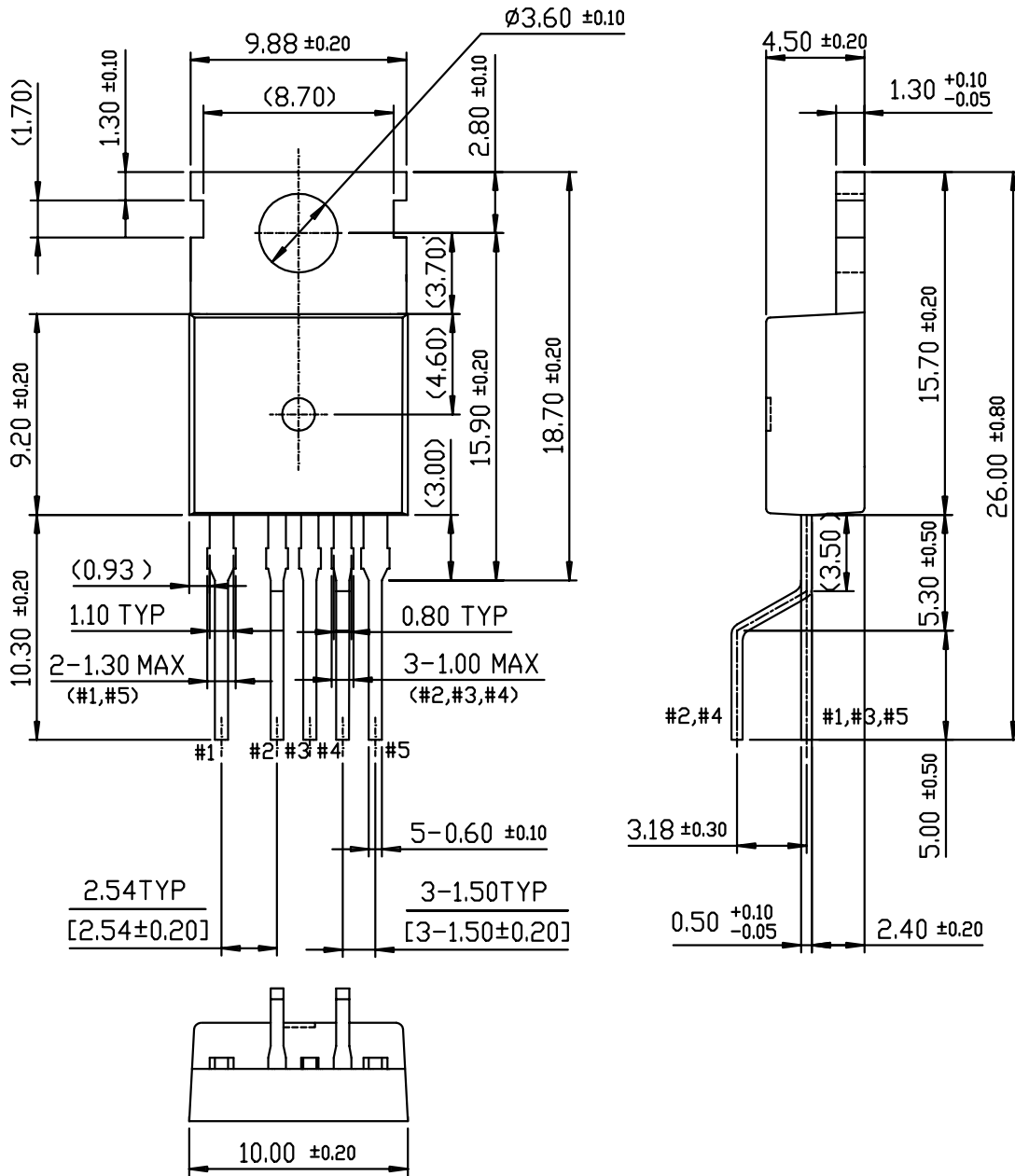
Package Dimensions (Continued)

TO-220-5L



Package Dimensions (Continued)

TO-220-5L(Forming)



## Ordering Information

Product Number	Package	Marking Code	BVDSS	FOSC	RDS(on)
KA5H0265RCTU	TO-220-5L	5H0265RC	650V	100kHz	5Ω
KA5H0265RCYDTU	TO-220-5L(Forming)				
KA5M0265RTU	TO-220F-4L	5M0265R	650V	67kHz	5Ω
KA5M0265RYDTU	TO-220F-4L(Forming)				
KA5L0265RTU	TO-220F-4L	5L0265R	650V	50kHz	5Ω
KA5L0265RYDTU	TO-220F-4L(Forming)				
Product Number	Package	Marking Code	BVDSS	FOSC	RDS(on)
KA5H0280RTU	TO-220F-4L	5H0280R	800V	100kHz	5.6Ω
KA5H0280RYDTU	TO-220F-4L(Forming)				
KA5M0280RTU	TO-220F-4L	5M0280R	800V	67kHz	5.6Ω
KA5M0280RYDTU	TO-220F-4L(Forming)				
Product Number	Package	Marking Code	BVDSS	FOSC	RDS(on)
KA5H02659RN	8-DIP	5H02659R	650V	100kHz	5Ω
KA5M02659RN	8-DIP	5M02659R	650V	67kHz	5Ω

TU : Non Forming Type

YDTU : Forming Type

**DISCLAIMER**

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

**LIFE SUPPORT POLICY**

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

ON Semiconductor and  are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at [www.onsemi.com/site/pdf/Patent-Marking.pdf](http://www.onsemi.com/site/pdf/Patent-Marking.pdf). ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

## PUBLICATION ORDERING INFORMATION

### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor  
19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA  
**Phone:** 303-675-2175 or 800-344-3860 Toll Free USA/Canada  
**Fax:** 303-675-2176 or 800-344-3867 Toll Free USA/Canada  
**Email:** [orderlit@onsemi.com](mailto:orderlit@onsemi.com)

**N. American Technical Support:** 800-282-9855 Toll Free  
USA/Canada  
**Europe, Middle East and Africa Technical Support:**  
Phone: 421 33 790 2910  
**Japan Customer Focus Center**  
Phone: 81-3-5817-1050

**ON Semiconductor Website:** [www.onsemi.com](http://www.onsemi.com)  
**Order Literature:** <http://www.onsemi.com/orderlit>  
For additional information, please contact your local  
Sales Representative